NSN 5961-01-462-9586

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-462-9586 **Inclosure Material:** Ceramic **Overall Length:** Between 1.397 inches and 1.651 inches **Overall Diameter:** Between 2.997 inches and 3.150 inches **Mounting Method:** Press fit **Features Provided:** W/heat sink **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 0.410 reverse voltage, average **Current Rating Per Characteristic:** 500.00 microamperes operating voltage dc minor **Capacitance Rating In Picofarads:** 0.3 **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius ambient air **Special Features:** Series resistance 7.0 ohms **Terminal Type And Quantity:** 2 binding post Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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